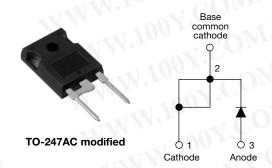
COMPLIANT



### Vishay High Power Products

# HEXFRED® Ultrafast Soft Recovery Diode, 15 A



勝 特 力 材 料 886-3-5753170 胜特力电子(上海) 86-21-34970699 胜特力电子(深圳) 86-755-83298787 Http://www.100y.com.tw

PRODUCT SUMMARY	11007.		
$V_R$	600 V		
V <sub>F</sub> at 15 A at 25 °C	1.7 V		
I <sub>F(AV)</sub>	15 A		
t <sub>rr</sub> (typical)	19 ns		
T <sub>J</sub> (maximum)	150 °C		
Q <sub>rr</sub> (typical)	80 nC		
dl <sub>(rec)M</sub> /dt (typical) at 125 °C	160 A/μs		
I <sub>RRM</sub> (typical)	4.0 A		

### **FEATURES**

- Ultrafast recovery
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- · Specified at operating conditions
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level

#### BENEFITS

- Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

#### **DESCRIPTION**

HFA15PB60 is a state of the art ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 15 A continuous current, the HFA15PB60 is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>RRM</sub>) and does not exhibit any tendency to "snap-off" during the tb portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA15PB60 is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS	WW		TW	
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	$V_{R}$		600	V
Maximum continuous forward current	I <sub>F</sub>	T <sub>C</sub> = 100 °C	15	<del></del>
Single pulse forward current	I <sub>FSM</sub>	NY.	150	Α
Maximum repetitive forward current	I <sub>FRM</sub>	111111111111111111111111111111111111111	60	
M. day day day	D 11	T <sub>C</sub> = 25 °C	74	10/
Maximum power dissipation	P <sub>D</sub>	T <sub>C</sub> = 100 °C	29	W
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C

<sup>\*</sup> Pb containing terminations are not RoHS compliant, exemptions may apply

## HFA15PB60PbF

# Vishay High Power Products HEXFRED® Ultrafast Soft Recovery Diode, 15 A



<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		600	400	I.C.	) IV-
	In	I <sub>F</sub> = 15 A		- T 1	1.3	1.7	V
Maximum forward voltage	$V_{FM}$	I <sub>F</sub> = 30 A	See fig. 1	1	1.5	2.0	
	11100	I <sub>F</sub> = 15 A, T <sub>J</sub> = 125 °C		-31	1.2	1.6	401
Maximum reverse	1.00	V <sub>R</sub> = V <sub>R</sub> rated	0	7 74	1.0	10	
leakage current	IRM	$T_J = 125$ °C, $V_R = 0.8 \times V_R$ rated	See fig. 2	-	400	1000	μA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	See fig. 3	AN W	25	50	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from p	ackage body	-	12	In	nH

PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Reverse recovery time See fig. 5, 10	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, dI_F/dt = 200$	) A/μs, V <sub>R</sub> = 30 V	-	19	-11	U0 x
	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	42	60	ns
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	74	120	100
Peak recovery current See fig. 6	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	4.0	6.0	Α
	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	6.5	10	
Reverse recovery charge See fig. 7 Peak rate of fall of recovery current during t <sub>b</sub> See fig. 8	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		T -	80	180	nC
	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	220	600	
	dI <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C	COM.		188		- A/µs
	dI <sub>(rec)M</sub> /dt2	T <sub>J</sub> = 125 °C	T. OM.T	-	160	- '	Ανμο

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s		-	300	°C
Thermal resistance, junction to case	R <sub>thJC</sub>	CO	1	- (X)	1.7	
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	M	- 1	40	K/W
Thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, flat, smooth and greased		0.25	-	
Weight			-	6.0	-	g
		100		0.21	-	oz.
Mounting torque	WIT	WW 100Y	6.0 (5.0)		12 (10)	kgf · cm (lbf · in)
Marking device	Nir.	Case style TO-247AC modified (JEDEC) HFA15PB60		5PB60		

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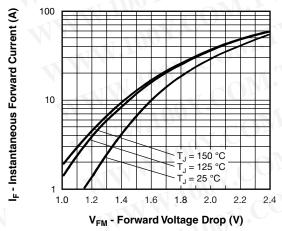


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current

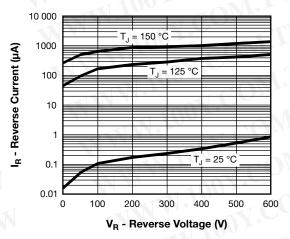


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

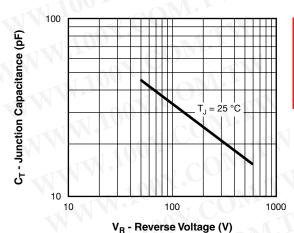


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

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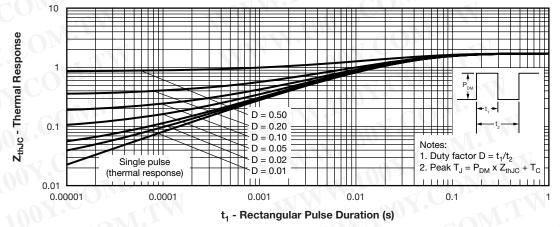


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics

## Vishay High Power Products

# HEXFRED® Ultrafast Soft Recovery Diode, 15 A



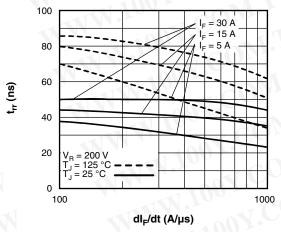


Fig. 5 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

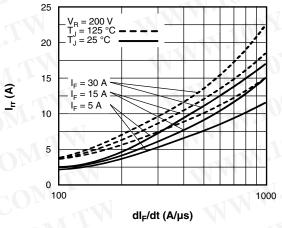


Fig. 6 - Typical Recovery Current vs. dl<sub>F</sub>/dt

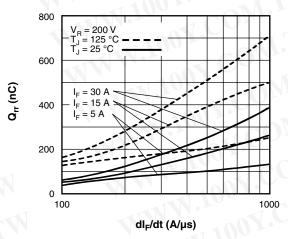


Fig. 7 - Typical Stored Charge vs. dl<sub>F</sub>/dt

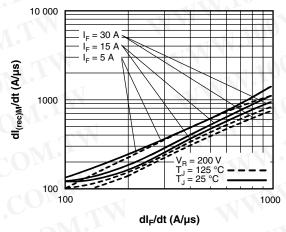


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $dI_F/dt$ 

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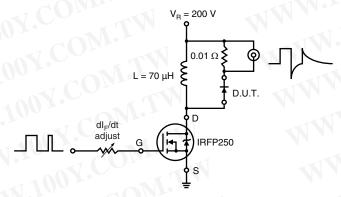
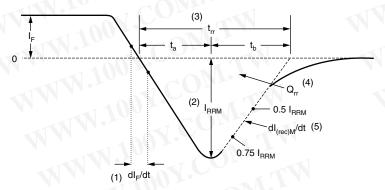


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl<sub>F</sub>/dt rate of change of current through zero crossing
- (2)  $I_{RRM}$  peak reverse recovery current
- (3)  $\rm t_{rr}$  reverse recovery time measured from zero crossing point of negative going  $\rm I_F$  to point where a line passing through 0.75  $\rm I_{RRM}$  and 0.50  $\rm I_{RRM}$  extrapolated to zero current.
- (4)  $\mathbf{Q}_{\rm rr}$  area under curve defined by  $\mathbf{t}_{\rm rr}$  and  $\mathbf{I}_{\rm RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dl_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$ 

Fig. 10 - Reverse Recovery Waveform and Definitions

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### HFA15PB60PbF

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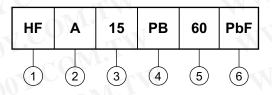
## HEXFRED®





### **ORDERING INFORMATION TABLE**

**Device code** 



HEXFRED® family

1 Process designator: A = Electron irradiated

B = Platinum diffused

3 Current rating (15 = 15 A)

Package outline (PB = TO-247, 2 pins)

Voltage rating (60 = 600 V)

• None = Standard production

• PbF = Lead (Pb)-free

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?95253				
Part marking information	www.vishay.com/doc?95255				

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